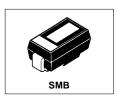
International Rectifier

MBRS120

SCHOTTKY RECTIFIER

1 Amp



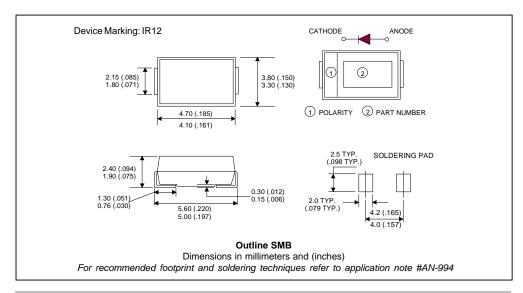
Major Ratings and Characteristics

| Characteristics | MBRS120 | Units | |
|---|-------------|-------|--|
| I _{F(AV)} Rectangular waveform | 1.0 | Α | |
| V _{RRM} | 20 | ٧ | |
| I _{FSM} @t _p =5μs sine | 310 | А | |
| V _F @ 1.0Apk,T _J =125°C | 0.35 | ٧ | |
| T _J range | - 65 to 150 | °C | |

Description/Features

The MBRS120 surface-mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Small foot print, surface mountable
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability





Voltage Ratings

| Part number | MBRS120 |
|--|---------|
| V _R Max. DC Reverse Voltage (V) | 20 |
| V _{RWM} Max. Working Peak Reverse Voltage (V) | 20 |

Absolute Maximum Ratings

| | Parameters | Value | Units | Conditions | |
|--------------------|------------------------------------|-------|-------|---|--|
| I _{F(AV)} | Max. Average Forward Current | 1.0 | Α | 50% duty cycle @ T _L = 138°C, rectangular wave for | |
| I _{FSM} | Max. Peak One Cycle Non-Repetitive | 310 | | 5μs Sine or 3μs Rect. pulse | Following any rated load condition and |
| | Surge Current | 40 | | 10ms Sine or 6ms Rect. pulse | with rated V _{RRM} applied |
| E _{AS} | Non Repetitive Avalanche Energy | 2.0 | mJ | T _J =25 °C, I _{AS} =1A, L=4mH | |
| I _{AR} | Repetitive Avalanche Current | 0.8 | А | Current decaying linearly to zero in 1 µsec Frequency limited by T _J max. Va = 1.5 x Vr typical | |

Electrical Specifications

| | Parameters | Тур. | Max. | Units | Conditio | ns |
|-----------------|----------------------------------|-------|-------|-------|---|---------------------------|
| V _{FM} | Max. Forward Voltage Drop (1) | 0.42 | 0.45 | V | @ 1A | T 25 %C |
| | | 0.46 | 0.52 | V | @ 2A | T _J = 25 °C |
| | | 0.33 | 0.37 | V | @ 1A | T 400.00 |
| | | 0.39 | 0.45 | V | @ 2A | T _J = 100 °C |
| | | 0.30 | 0.35 | V | @ 1A | T 405.00 |
| | | 0.36 | 0.43 | V | @ 2A | T _J = 125 °C |
| I _{RM} | Max. Reverse Leakage Current (1) | 0.015 | 0.2 | mA | T _J = 25 °C | |
| | | 2.0 | 6.0 | mA | T _J = 100 °C | $V_R = rated V_R$ |
| | | 7.0 | 20 | mA | T _J = 125 °C | |
| C _T | Typical Junction Capacitance | 110 | - | pF | $V_R = 5V_{DC}$ (te | st signal range 100kHz to |
| | | | | | 1Mhz), @ 25° | C |
| L _S | Typical Series Inductance | 2.0 | - | nH | Measured lead to lead 5mm from package body | |
| dv/dt | Max. Voltage Rate of Change | - | 10000 | V/ µs | (Rated V _R) | |

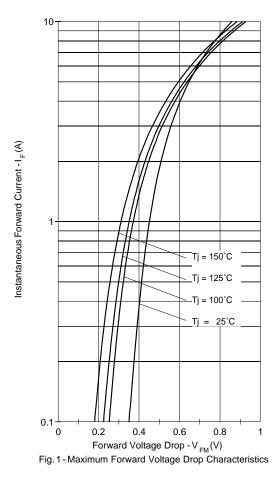
⁽¹⁾ Pulse Width < 300 μ s, Duty Cycle < 2%

Thermal-Mechanical Specifications

| | Parameters | Value | Units | Conditions |
|-------------------|---|-------------|---------|------------------|
| T _J | Max. Junction Temperature Range (*) | -65 to 150 | °C | |
| T _{stg} | Max. Storage Temperature Range | -65 to 150 | °C | |
| R _{thJL} | Max. Thermal Resistance Junction to Lead (**) | 30 | °C/W | DC operation |
| R _{thJA} | Max. Thermal Resistance Junction to Ambient | | 80 | °C/W |
| Wt | Approximate Weight | 0.10(0.003) | gr (oz) | |
| | Case Style | SMB | | Similar DO-214AA |
| | Device Marking | IR12 | | |

 $[\]frac{\text{(*) dPtot}}{\text{dTi}} < \frac{1}{\text{Rth(j-a)}} \text{ thermal runaway condition for a diode on its own heatsink}$

^(**) Mounted 1 inch square PCB



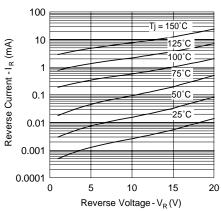


Fig. 2 - Typical Peak Reverse Current Vs. Reverse Voltage

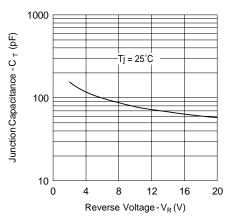


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

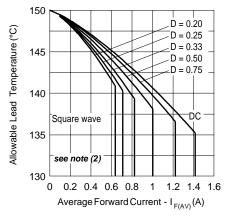


Fig. 4 - Maximum Average Forward Current Vs. Allowable Lead Temperature

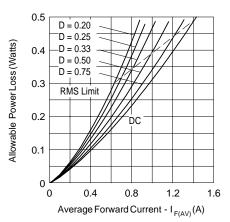


Fig. 5 - Maximum Average Forward Dissipation Vs. Average Forward Current

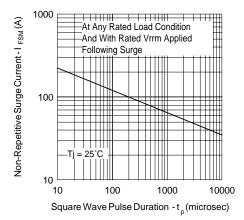
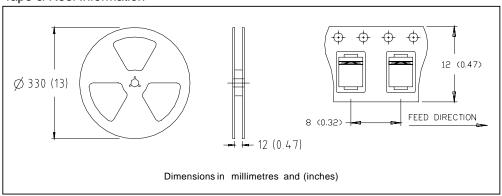


Fig. 6 - Maximum Peak Surge Forward Current Vs. Pulse Duration

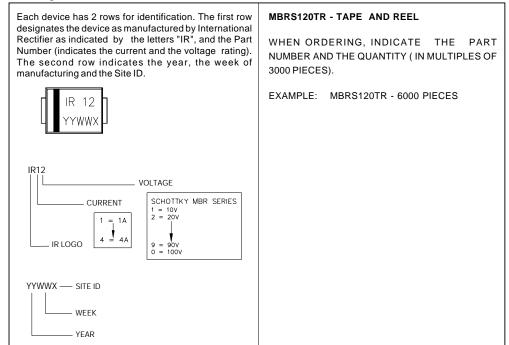
(2) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $\label{eq:pd} \textit{Pd=ForwardPowerLoss=I}_{F(AV)} x \, V_{FM} \, @ \, (I_{F(AV)} / \, D) \ \, (\text{see Fig. 6});$ $Pd_{REV} = Inverse Power Loss = V_{R1} \times I_{R} (1 - D)$

Tape & Reel Information



Marking & Identification

Ordering Information



MBRS120

Bulletin PD-20644 rev. D 03/03

Data and specifications subject to change without notice.
This product has been designed for Industrial Level.
Qualification Standards can be found on IR's Web site.



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